

Digital Transistor (Dual Digital Transistors for Inverter Drive)

IMD8A

●Features

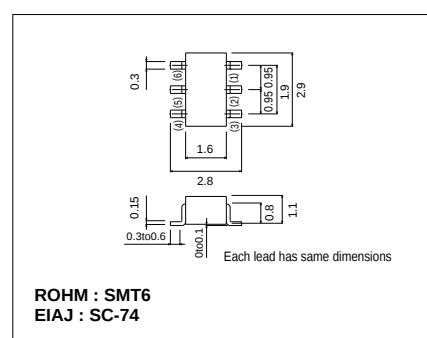
1) Both the DTA144T chip and DTC144T chip in a SMT package.

●Absolute maximum ratings (Ta = 25°C)

Parameter	Symbol	Limits	Unit
Collector-base voltage	V _{CB0}	50	V
Collector-emitter voltage	V _{CE0}	50	V
Emitter-base voltage	V _{EB0}	5	V
Collector current	I _c	100	mA
Collector power dissipation	P _c	300(TOTAL)	mW *
Storage temperature	T _{stg}	-55~+150	°C

* 200mW per element must not be exceeded. PNP type negative symbols have been omitted.

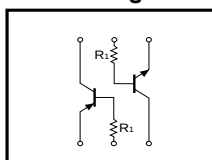
●External dimensions (Units : mm)



●Package, marking, and packaging specifications

Type	IMD8A
Package	SMT6
Marking	D8
Code	T108
Basic ordering unit (pieces)	3000

●Circuit diagram



●Electrical characteristics (Ta = 25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-base breakdown voltage	BV _{CB0}	50	—	—	V	I _c = 50μA
Collector-emitter breakdown voltage	BV _{CE0}	50	—	—	V	I _c = 1mA
Emitter-base breakdown voltage	BV _{EB0}	50	—	—	V	I _e = 50μA
Collector cutoff current	I _{cbo}	—	—	0.5	μA	V _{CB} = 50V
Emitter cutoff current	I _{ebo}	—	—	0.5	μA	V _{EB} = 4V
Collector-emitter saturation voltage	V _{CE(sat)}	—	—	0.3	V	I _c = 5mA, I _B = 0.5mA
DC current transfer ratio	h _{FE}	100	250	600	—	V _{CE} = 5V, I _c = 1mA
Input resistance	R _i	32.9	47	61.1	kΩ	—

PNP type negative symbols have been omitted.